

September 12, 2003

To: Commissioner for Patents
P.O.Box 1450
Alexandria, VA 22313-1450

Fr: George O. Saile, Reg. No. 19,572
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Subject: | Serial No. 10/602,229 06/24/03 |
| Shih-Wei Wang |
A NOVEL DUAL BIT SPLIT GATE FLASH
MEMORY
Grp. Art Unit:
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INFORMATION DISCLOSURE STATEMENT

Enclosed is Form PTO-1449, Information Disclosure Citation
In An Application.

The following Patents and/or Publications are submitted to
comply with the duty of disclosure under CFR 1.97-1.99 and
37 CFR 1.56. Copies of each document is included herewith.

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being
deposited with the United States Postal Service as first class
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P.O. Box 1450, Alexandria, VA 22313-1450, on September , 2003.

Stephen B. Ackerman, Reg.# 37761

Signature/Date _____

U.S. Patent 6,462,375 to Wu, "Scalable Dual-Bit Flash Memory Cell and Its Contactless Flash Memory Array," discloses two floating gates having a shared select gate/control gate therebetween.

The following three U.S. Patents to Harari et al., all entitled "Dual Floating Gate EEPROM Cell Array with Steering Gates Shared by Adjacent Cells," disclose floating gates on the sidewalls of a select gate:

- 1) U.S. Patent 6,151,248.
- 2) U.S. Patent 6,344,993.
- 3) U.S. Patent 6,266,278.

The following three U.S. Patents to Ogura et al., all entitled "Process for Making and Programming and Operating a Dual-Bit Multi-Level Ballistic Flash Memory," describe two floating gates on the sidewalls of a select gate wherein a control gate separates each set of select gate/floating gates:

- 1) U.S. Patent 6,133,098.
- 2) U.S. Patent 6,366,500.
- 3) U.S. Patent 6,359,807.

Sincerely,

Stephen B. Ackerman,
Reg. No. 37761

INFORMATION DISCLOSURE CITATION IN AN APPLICATION <small>(Use several sheets if necessary)</small>				Document Number (Opinion) TSMC-02-695	Application Number 10/602,229	
				Examiner Shih-Wei Wang		
				Date Rec'd 06/24/03	Drawn At U.S.	
U. S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	REASON DATE X APPROPRIATE
	6462375	10/8/02	Wu	257	316	4/1/02
	6151248	11/21/00	Harari et al.	365	185.14	6/30/99
	6344993	2/5/02	Harari et al.	365	185.01	7/13/01
	6266278	7/24/01	Harari et al.	365	185.18	8/8/00
	6133098	10/17/00	Ogura et al.	438	267	5/17/99
	6366500	4/2/02	Ogura et al.	365	185.29	9/6/00
	6359807	3/19/02	Ogura et al.	365	185.18	9/6/00
FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
OTHER DOCUMENTS <small>(Including Author, Title, Date, Page No., Etc.)</small>						
EXAMINER			DATE CONSIDERED			

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through